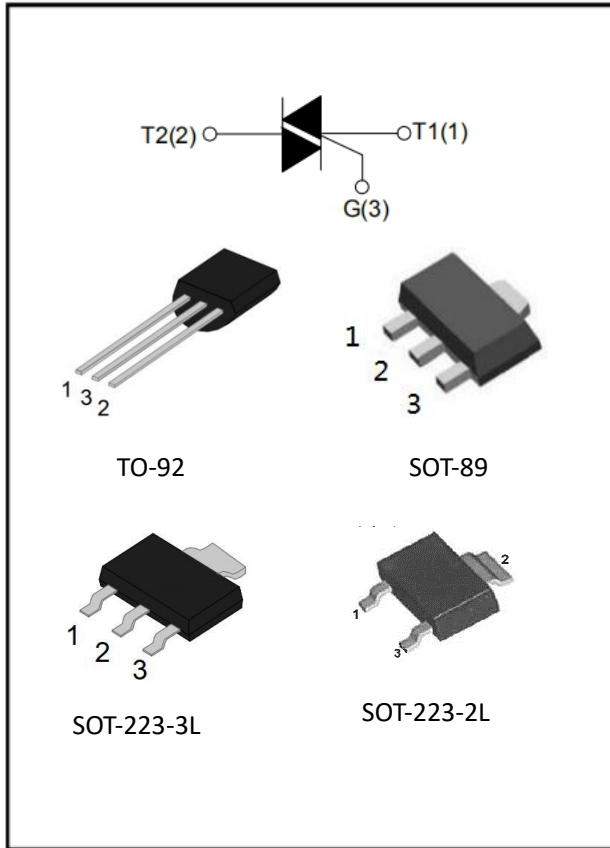


1A 4Q Triac



Features

- On-state rms current, $I_{T(RMS)}$ 1 A
- Repetitive peak off-state voltage, V_{DRM}/V_{RRM} 800 V
- Triggering gate current, $I_{GT}(Q1)$ 5 mA
- Glass-passivated mesa chip for reliability and uniform.

Applications

- General purpose switching and phase control
- General purpose low power switching
- Solid-state relay

Mechanical Data

- **Case Material:** "Green" Molding Compound
- **Package:**

DEVICE	PACKAGE
ACY0810S2	SOT-223-3L
ACY0810S3	SOT-89
ACY0810T9	TO-92
ACY0810S4	SOT-223-2L

Main Characteristics

SYMBOL	LIMITS	UNIT
$I_{T(RMS)}$	1	A
V_{DRM}/V_{RRM}	800	V
I_{GT}	5	mA

Maximum Ratings

PARAMETER	SYMBOL	LIMITS	UNIT
Storage junction temperature range	T_{stg}	-40~150	°C
Operating junction temperature range	T_j	-40~125	°C
Repetitive surge peak Off-state voltage ($T_j=25^{\circ}C$)	V_{DRM}	800	V
Repetitive peak reverse voltage ($T_j=25^{\circ}C$)	V_{RRM}	800	V
RMS on-state current	$I_{T(RMS)}$	1	A
Non-repetitive surge peak on-state current (full sine wave, $t_p=20ms, T_j=25^{\circ}C$)	I_{TSM}	10	A
I^2t value for fusing ($t_p=10ms$)	I^2t	1.28	A ² s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$)	di/dt	I - II - III	50
		IV	20
Peak gate current	I_{GM}	2	A
Average gate power dissipation	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	5	W



ACY0810 Series

■Electrical Characteristics (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	QUADRANT	MIN	TYP	MAX
Gate trigger current	I _{GT}	mA	V _D =12V, R _L =33Ω	I - II-III			5
				IV			10
Gate trigger voltage	V _{GT}	V	V _D =12V, R _L =33Ω	I - II-III-IV			1.3
Non-triggering gate voltage	V _{GD}	V	V _D =V _{DRM}	I - II-III-IV	0.2		
Holding current	I _H	mA	I _T =100mA	I - II-III-IV			7
Latching current	I _L	mA	I _G =1.2 I _{GT}	I - III-IV			5
				II			20
Rate of rise of off-state voltage	dV/dt	V/μs	V _D =0.66×V _{DRM} T _j =125°C Gate open	I - II-III-IV	50		

■Static Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MAX
Peak on-state voltage	V _{TM}	V	I _{TM} =1.4A t _p =380μs, T _j =25°C	1.5
Peak off-state current	I _{DRM} I _{RRM}	μA	V _{DRM} = V _{RRM} , T _j =25°C	10
Peak reverse current		mA	V _{DRM} = V _{RRM} , T _j =125°C	0.5

■Thermal Resistance

PARAMETER		SYMBOL	UNIT	Pacakge	Value
Thermal Resistance (Typical)	Junction to case	R _{θJ-C}	°C/W	TO-92	60
			°C/W	SOT-89	31
			°C/W	SOT-223	18

■ Characteristics (Typical)

FIG.1: Maximum power dissipation versus RMS on-state current

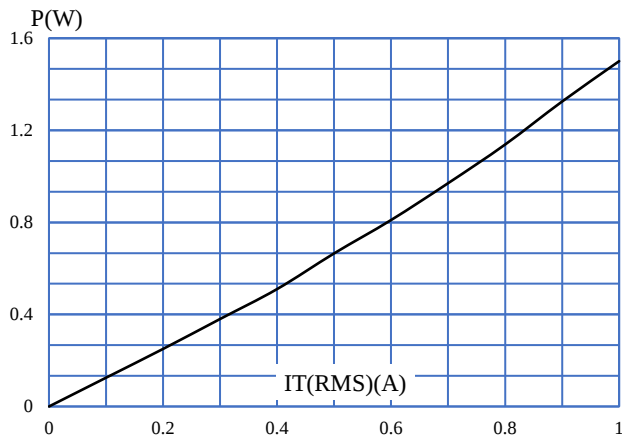


FIG.2: RMS on-state current versus case temperature

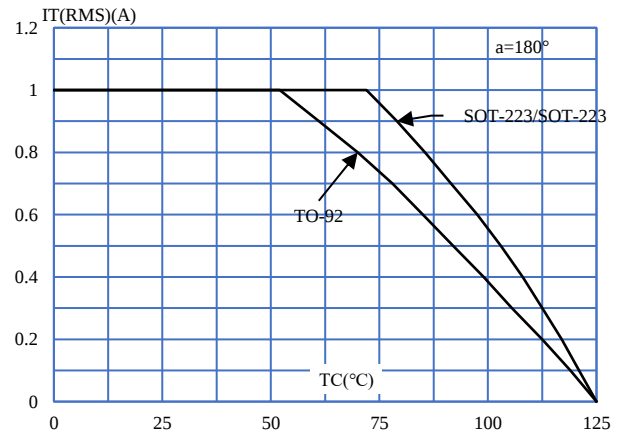


FIG.3: Surge peak on-state current versus number of cycles

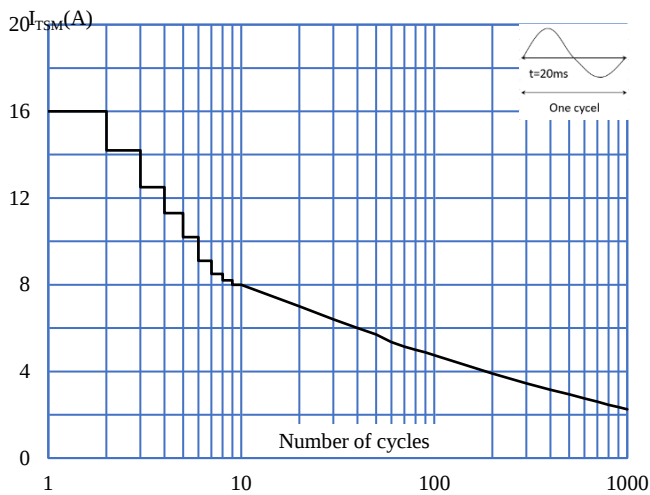


FIG.4: On-state characteristics (maximum values)

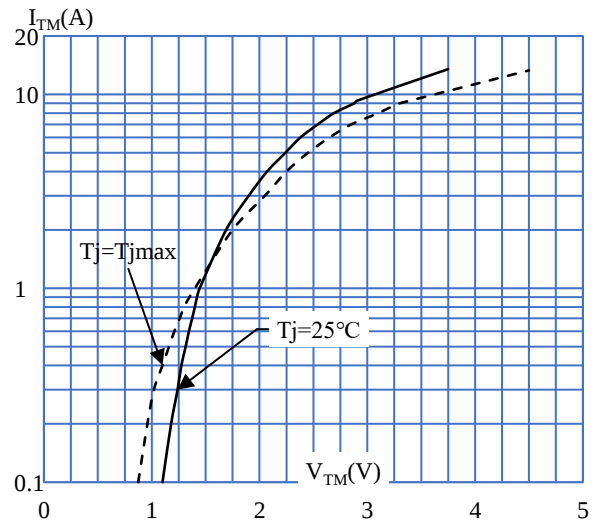


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$, and corresponding value of $I_2 t$ ($dI/dt < 50A/\mu s$)

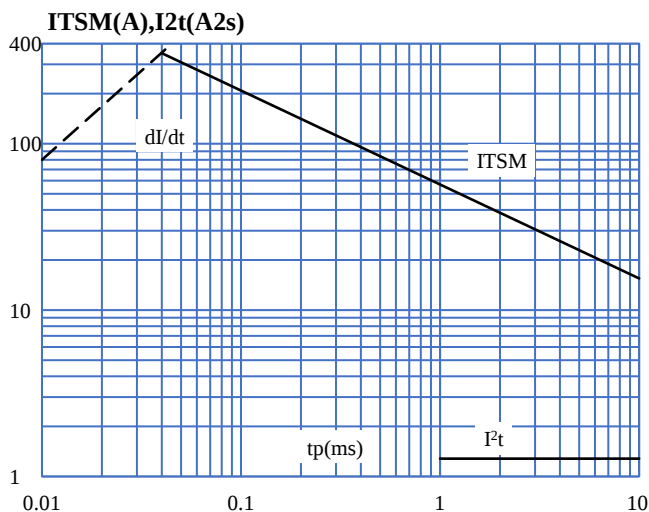
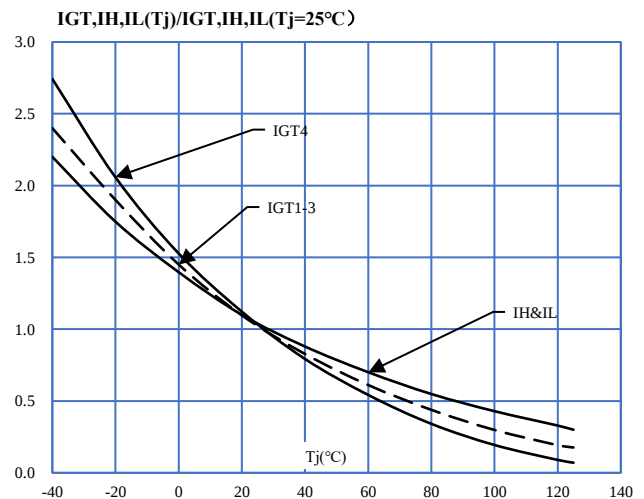


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

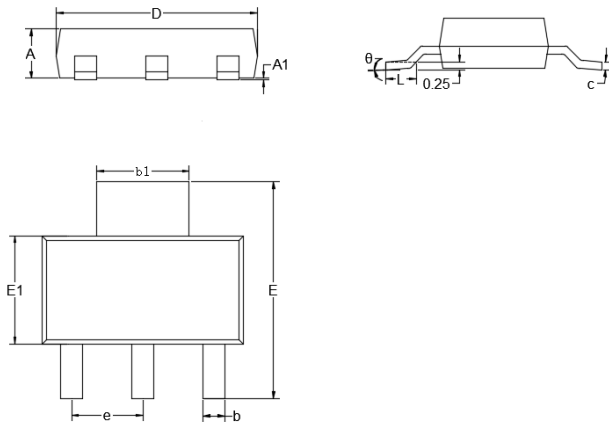




ACY0810 Series

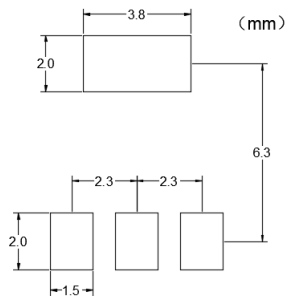
■ Outline Dimensions

➤ SOT-223-3L Package Outline Dimensions

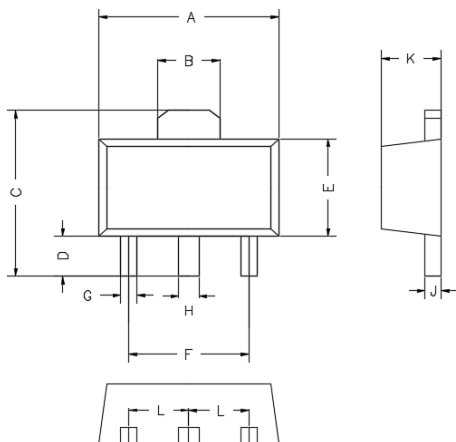


SOT-223-3L Suggested Pad Layout

DIMENSIONS				
DIM	INCHES		MM	
	MIN	MAX	MM	MAX
A	0.0591	0.0670	1.5000	1.7000
A1	0.0008	0.0039	0.0200	0.1000
b	0.0259	0.0330	0.6600	0.8400
b1	0.1140	0.1220	2.9000	3.1000
c	0.0090	0.0138	0.2300	0.3500
D	0.2480	0.2640	6.3000	6.7000
E	0.2637	0.2874	6.7000	7.3000
E1	0.1290	0.1460	3.3000	3.7000
e	0.0866	0.0945	2.2000	2.4000
L	0.0295	0.0492	0.7500	1.2500
θ	0°	10°	0°	10°

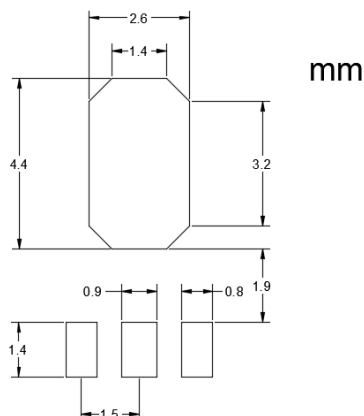


➤ SOT-89 Package Outline Dimensions



SOT-89 Suggested Pad Layout

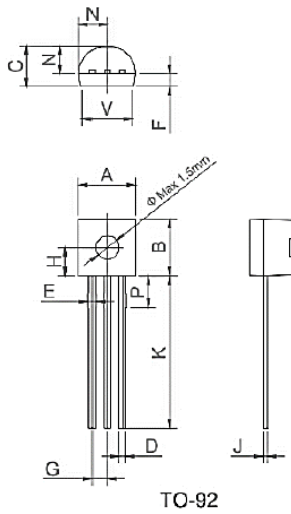
DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.169	0.185	4.30	4.70	
B	0.061		1.55		TYP
C	0.154	0.171	3.91	4.35	
D	0.031	0.047	0.80	1.20	
E	0.089	0.104	2.25	2.65	
F	0.118		3.00		TYP
G	0.013	0.020	0.33	0.52	
H	0.016	0.023	0.40	0.58	
J	0.014	0.017	0.35	0.44	
K	0.055	0.063	1.40	1.60	
L	0.059		1.50		TYP





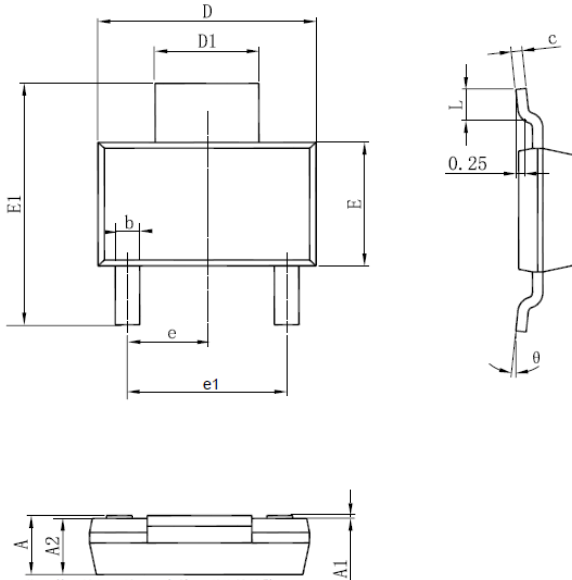
ACY0810 Series

➤ TO-92 Package Outline Dimensions



Ref.	Dimensions					
	Inches			Millimeters		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.175	0.181	0.205	4.45	4.6	5.2
B	0.17	0.181	0.21	4.32	4.6	5.33
C	0.125	0.14	0.165	3.18	3.55	4.19
D	0.016		0.021	0.407		0.533
E	0.020		0.028	0.5		0.7
F	-	0.043	-	-	1.1	-
G	-	0.05	-	-	1.27	-
H	-	0.091	-	-	2.3	-
J	0.014	0.015	0.02	0.36	0.38	0.5
K	0.5		0.591	12.7		15
N	0.08	0.091	0.105	2.04	2.3	2.66
P	0.073		0.081	1.86		2.06
V			0.169			4.3

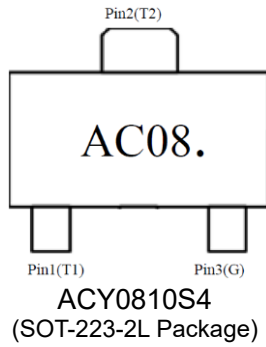
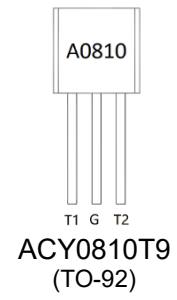
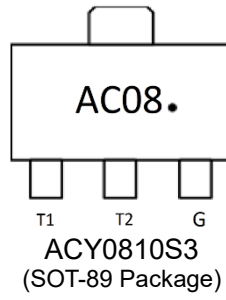
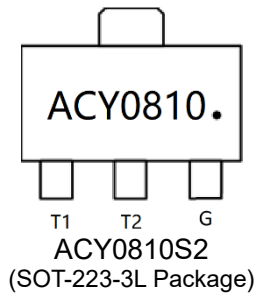
➤ SOT-223-2L Package Outline Dimensions



Ref.	Dimensions					
	Inches			Millimeters		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			0.0709	/	/	1.80
A1	0.00079		0.0039	0.02	/	0.10
A2	0.0591	0.063	0.0667	1.50	1.60	1.70
b	0.026	0.028	0.0331	0.66	0.71	0.84
c	0.0091	0.0118	0.0138	0.23	0.30	0.35
D	0.248	0.256	0.264	6.30	6.50	6.70
D1	0.114	0.118	0.122	2.90	3.00	3.10
E	0.13	0.138	0.146	3.30	3.50	3.70
E1	0.264	0.276	0.287	6.70	7.00	7.30
e	0.0906 BASIC			2.30 BASIC		
e1	0.181 BASIC			4.60 BASIC		
L	0.0295	/	/	0.75	/	/
θ	0°	/	10°	0°	/	10°



■ Marking Information





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